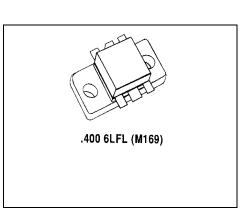


140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013 PHONE: (215) 631-9840 FAX: (215) 631-9855

F RF & MICROWAVE TRANSISTORS 800 / 900 MHz APPLICATIONS

Features

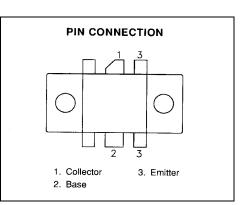
- 900 MHz
- 24 VOLTS
- **P**_{OUT} = 60 WATTS
- $G_P = 7.0 \text{ dB MINIMUM}$
- INPUT AND OUTPUT MATCHED
- COMMON BASE CONFIGURATION



MS1536

DESCRIPTION:

The MS1536 is a 28V Class C epitaxial silicon NPN planar transistor designed primarily for UHF communications. This device utilizes diffused emitter resistors to achieve 10:1 VSWR capability under specified operating conditions. Internal input matching provides optimum power gain and efficiency over the 225 – 400 MHz band.



ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

| Symbol | Parameter | Value | Unit |
|-------------------|---------------------------|-------------|------|
| V _{сво} | Collector-Base Voltage | 55 | V |
| V _{CES} | Collector-Emitter Voltage | 55 | V |
| V _{EBO} | Emitter-Base Voltage | 4.0 | V |
| Ι _c | Device Current | 10 | Α |
| P _{DISS} | Power Dissipation | 175 | W |
| T _{STG} | Storage Temperature | -65 to +150 | °C |
| TJ | Junction Temperature | +200 | °C |

Thermal Data

| R _{TH(J-C)} | Thermal Resistance Junction-case | 1.0 | °C/W | | |
|----------------------|----------------------------------|-----|------|--|--|



MS1536

ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC

| Symbol | Test Conditions | | Value | | | |
|--------------------------|-----------------------|----------------------|-------|------|------|------|
| Symbol | Test conditions | | Min. | Typ. | Max. | Unit |
| BV _{CBO} | I _c = 50mA | $I_{E} = 0mA$ | 55 | | | V |
| BV _{CES} | I _c = 50mA | $V_{BE} = 0mA$ | 55 | | | V |
| BV _{CEO} | l _c = 50mA | $I_{B} = 0mA$ | 28 | | | V |
| BV _{EBO} | I _E = 10mA | $I_c = 0mA$ | 3.0 | | | V |
| I _{CES} | V _{CE} = 25V | I _E = 0mA | | | 10 | mA |
| HFE | $V_{CE} = 5V$ | $I_c = 2A$ | 20 | | 150 | |

DYNAMIC

| Symbol | I Test Conditions | | | Value | | | |
|----------------|-------------------|-----------------------|----------------|-------|------|------|------|
| Symbol | | Test conditions | | Min. | Typ. | Max. | Unit |
| Pout | f = 900 MHz | P _{IN} = 12W | $V_{CE} = 24V$ | 60 | | | W |
| G _P | f = 900 MHz | P _{IN} = 12W | $V_{CE} = 24V$ | 7.5 | | | dB |
| ηc | f = 900 MHz | P _⊪ = 12W | $V_{CE} = 24V$ | 55 | | | % |
| Сов | f = 1 MHz | $V_{CB} = 24 V$ | | | | 70 | pf |

IMPEDANCE DATA

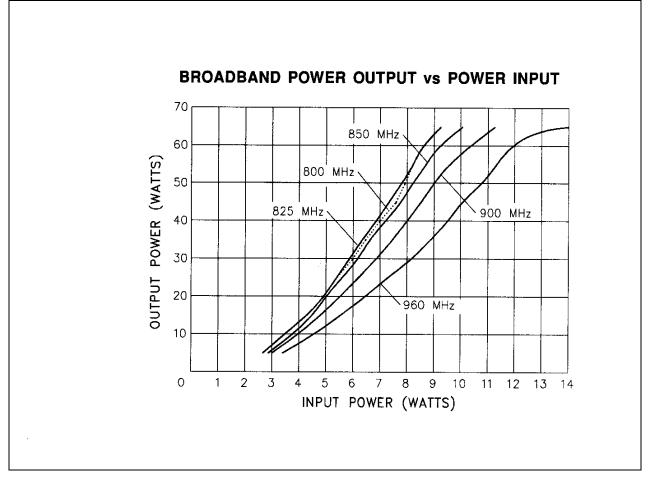
| $Z_{IN}(\Omega)$ | $Z_{CL}(\Omega)$ | | |
|------------------|--|--|--|
| 3.8 - j3.8 | 4.9 + j2.0 | | |
| 7.6 - j3.4 | 5.0 + j0.4 | | |
| 9.4 - j2.6 | 4.3 + j.06 | | |
| 10.8 + j1.0 | 4.3 + j0.5 | | |
| | 3.8 - j3.8 7.6 - j3.4 9.4 - j2.6 | | |

 $P_{OUT} = 60W$ $V_{CE} = 24V$



MS1536

TYPICAL PERFORMANCE





PACKAGE MECHANICAL DATA

